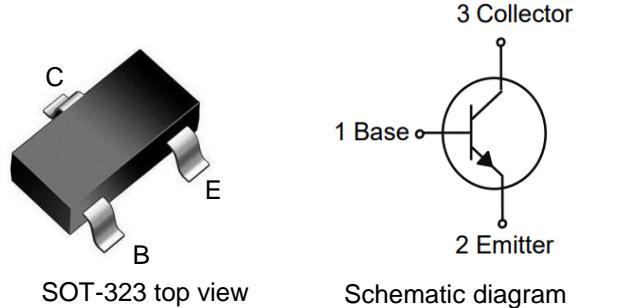


NPN Silicon Epitaxial Planar Transistor

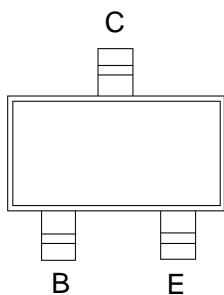
Features

- Low Noise and High Gain
- High Power Gain



Application

- low noise amplifier at VHF, UHF and CATV band applications



Marking and pin assignment



Pb-Free



RoHS



Halogen-Free

Maximum Ratings(Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	20	V
V_{CEO}	Collector-Emitter Voltage	12	V
V_{EBO}	Emitter-Base Voltage	3	V
I_C	Collector Current	100	mA
P_C	Collector Power Dissipation	150	mW
$R_{\Theta JA}$	Thermal Resistance From Junction To Ambient	625	°C/W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-50~+150	°C

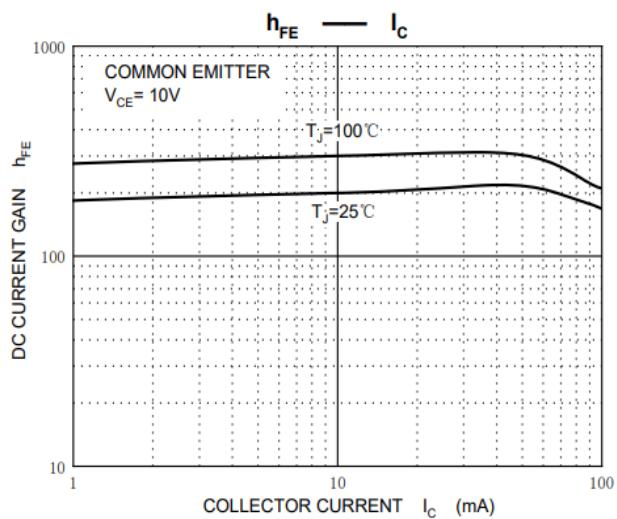
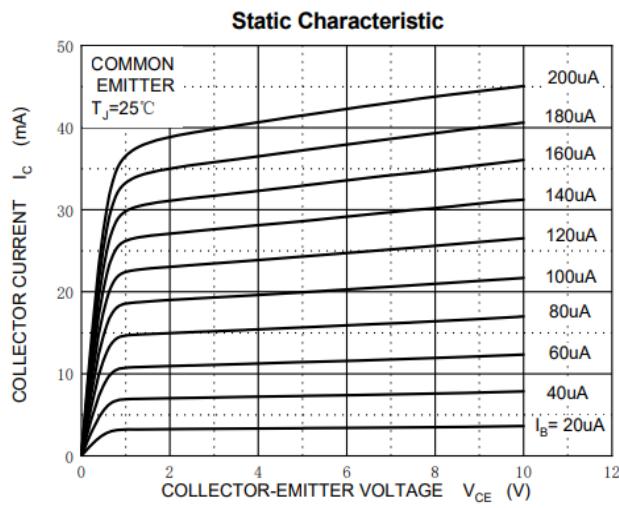
Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

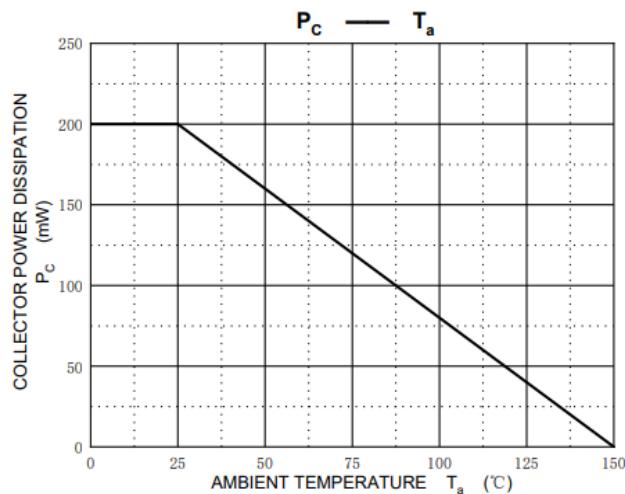
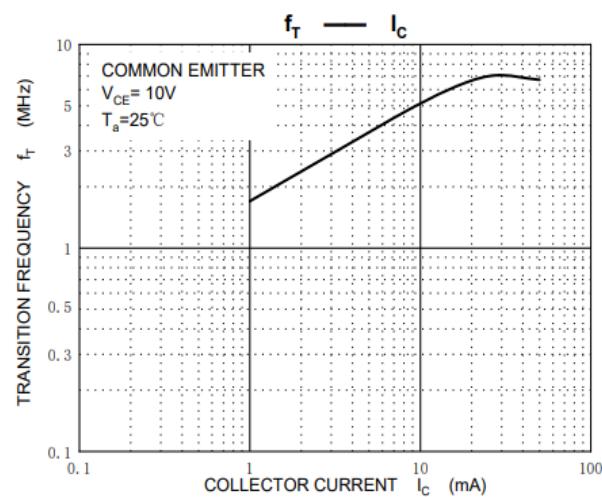
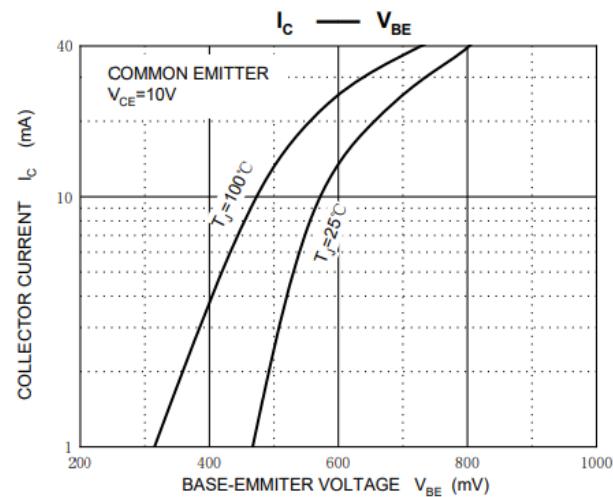
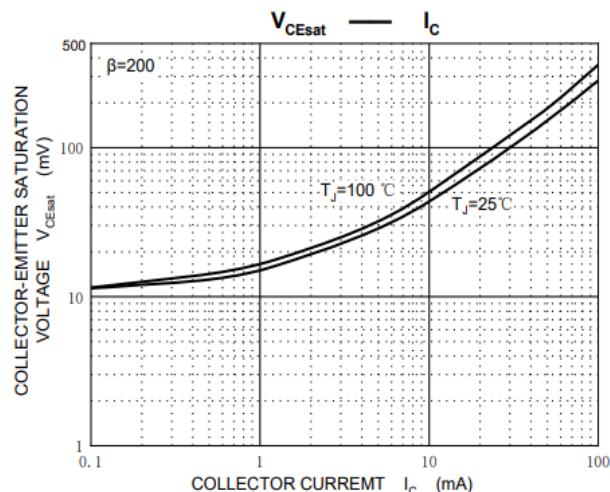
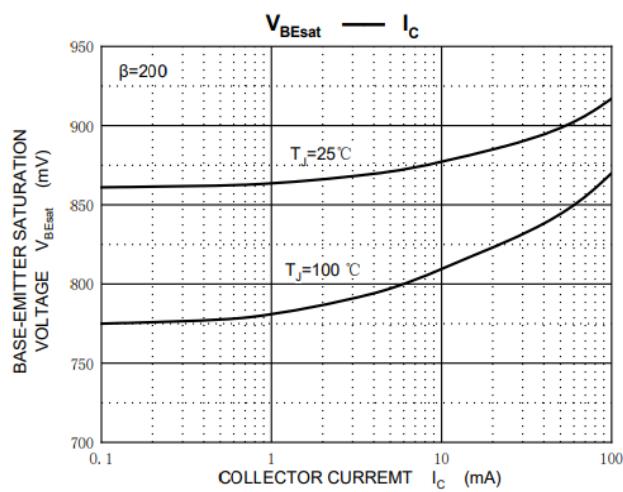
Symbol	Parameter	Condition	Min	Typ	Max	Unit
$V_{(\text{BR})\text{CBO}}$	Collector-base breakdown voltage	$I_C=100\mu\text{A}, I_E=0$	20	--	--	V
$V_{(\text{BR})\text{CEO}}$	Collector-emitter breakdown voltage	$I_C=1\text{mA}, I_B=0$	12	--	--	V
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage	$I_E=100\mu\text{A}, I_C=0$	3	--	--	V
I_{CBO}	Collector cut-off current	$V_{\text{CB}}=10\text{ V}, I_E=0$	--	--	1	μA
I_{EBO}	Emitter cut-off current	$V_{\text{EB}}=1\text{ V}, I_C=0$	--	--	1	μA
h_{FE}	DC current gain	$V_{\text{CE}}=3\text{V}, I_C= 7\text{mA}$	40	--	250	
$V_{\text{CE}(\text{sat})}$	Collector-emitter saturation voltage	$I_C=50\text{ mA}, I_B= 5\text{mA}$	--	--	0.3	V
$V_{\text{BE}(\text{sat})}$	Base-emitter saturation voltage	$I_C=50\text{ mA}, I_B= 5\text{mA}$	--	--	1.15	V
N_F	Noise Figure	$V_{\text{CB}}=3\text{V}, I_C=7\text{mA}, f=1\text{GHz}$	--	1.2	2.5	dB
C_{ob}	Collector output capacitance	$V_{\text{CE}}=3\text{V}, I_E=7\text{mA}, f=1\text{GHz}$	--	0.7	1.5	pF
f_T	Transition frequency	$V_{\text{CE}}=3\text{V}, I_C= 7\text{mA}$	--	4.5	--	GHz

Classification of hFE

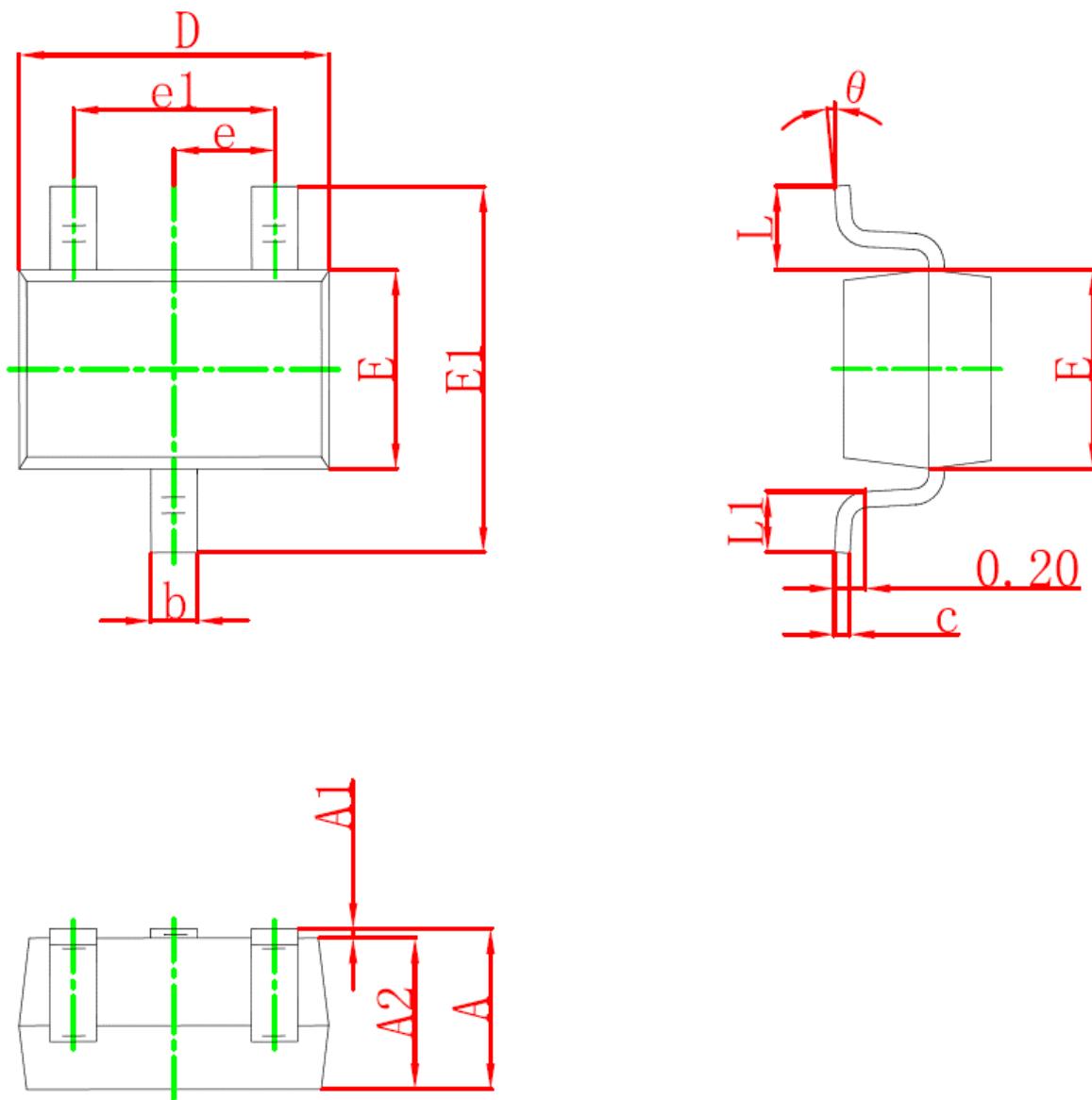
Marking	R23	R24	R25
Range	40-80	70-140	125-250

Typical Operating Characteristics





SOT-323 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650TYP		0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525REF		0.021REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°